



	ITC135P	Units
Relay Load Voltage	350	V
Relay Load Current	120	mA
Relay Max R_{ON}	15	Ω
Bridge Rectifier Reverse Voltage	100	V
Darlington Collector Current	120	mA
Darlington Current Gain	10,000	-

Description

The Integrated Telecom Circuit combines a 1-Form-A solid state relay, bridge rectifier, Darlington transistor, optocoupler and zener diodes into one 16 pin SOIC package, consolidating designs and reducing component count in telecom applications. The ITC135P's optocoupler provides half wave ring detection.

Features

- Small 16 Pin SOIC Package (PCMCIA Compatible)
- Board Space and Cost Savings
- 2mW Hookswitch Drive Power (Logic Compatible)
- No Moving Parts
- 3750V_{RMS} Input/Output Isolation
- FCC Compatible Part 68
- Full-Wave Bridge Rectifier
- Darlington Transistor for Electronic Inductor "Dry" Circuits
- Half Wave Current Detector for Ring Signal or Loop Current Detect
- Current Limiting and Tape & Reel Versions Available
- JEDEC Standard Pin Out
- Includes Zener Diodes

Applications

- Data/Fax Modem
- Voice Mail Systems
- Telephone Sets
- Computer Telephony Integration
- Cable TV Modems

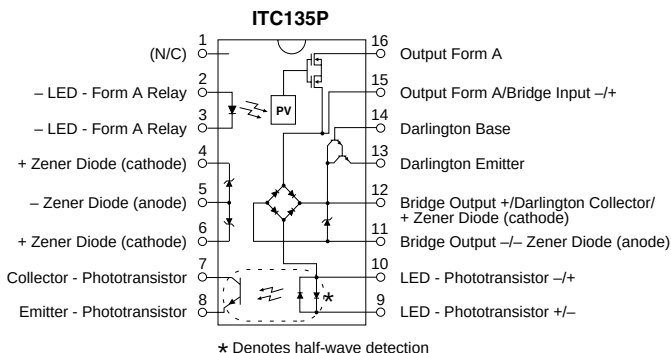
Approvals

- UL Recognized: File Number E76270
- CSA Certified: File Number LR 43639-12
- BSI Certified:
 - BS EN 60950:1992 (BS7002:1992) Certificate #: 7969
 - BS EN 41003:1993 Certificate #: 7969

Ordering Information

Part #	Description
ITC135P	16 Pin SOIC (50/Tube)
ITC135P	16 Pin SOIC (1000/Reel)

Pin Configuration



Absolute Maximum Ratings (@ 25° C)

Parameter	Min	Typ	Max	Units
Total Package Dissipation	-	-	1 ¹	W
Isolation Voltage				
Input to Output	3750	-	-	V _{RMS}
Operational Temperature	-40	-	+85	°C
Storage Temperature	-40	-	+125	°C
Soldering Temperature (10 Seconds Max.)	-	-	+220	°C

¹ Above 25° derate linearly 8.33mw/°C

Total Power Dissipation (PD):

$$P_D = P_{\text{HOOKSWITCH}} + P_{\text{BRIDGE}} + P_{\text{DARLINGTON}} + P_{\text{LED}}$$

$$P_D = (R_{DS(on)})(I_L^2) + 2(V_F)(I_L) + (V_{CE})(I_L) + (V_{LED})(I_F)$$

WHERE:

$R_{DS(on)}$ = Maximum reoly on resistance

I_L = Maximum loop current

V_F = Maximum diode forward voltage

V_{CE} = Maximum voltage collector to emitter

V_{LED} = Maximum LED forward voltage

I_F = Maximum LED current

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this data sheet is not implied. Exposure of the device to the absolute maximum ratings for an extended period may degrade the device and effect its reliability.

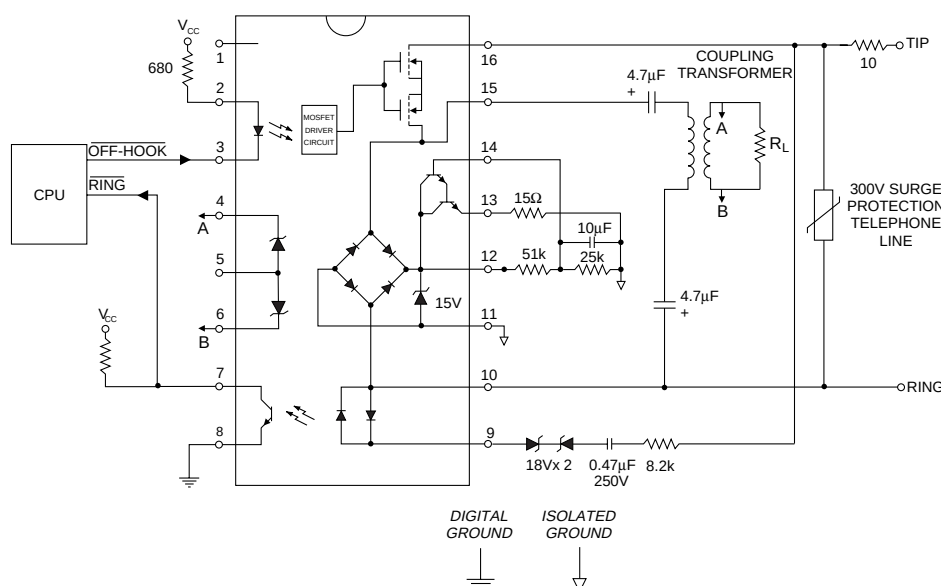
Electrical Characteristics

Parameter	Conditions	Symbol	Min	Typ	Max	Units
Relay Portion (Pins 15,16)						
Output Characteristics @ 25°C						
Load Voltage, DC or Peak AC	-	V_L	-	-	350	V
Load Current (Continuous)	-	I_L	-	-	120	mA
On-Resistance	$I_L=120\text{mA}$	R_{ON}	-	-	15	Ω
Off-State Leakage Current	$V_L=350, T_J=25^\circ\text{C}$	I_{LEAK}	-	-	1	μA
Switching Speeds						
Turn-On	$I_F=5\text{mA}, V_L=10\text{V}$	T_{ON}	-	-	3	ms
Turn-Off	$I_F=5\text{mA}, V_L=10\text{V}$	T_{OFF}	-	-	3	ms
Output Capacitance	50V, f=1MHz	C_{OUT}	-	25	-	pF
Relay Portion (Pins 2,3)						
Input Characteristics @ 25°C						
Input Control Current	$I_L=120\text{mA}$	I_F	5	-	50	mA
Input Voltage Drop	$I_F=5\text{mA}$	V_F	0.9	1.2	1.4	V
Reverse Input Voltage	-	V_R	-	-	5	V
Reverse Input Current	$V_R=5\text{V}$	I_R	-	-	10	μA
Detector Portion (Pins 7,8)						
Output Characteristics @ 25°C						
Phototransistor Blocking Voltage	$I_C=10\mu\text{A}$	BV_{CEO}	20	50	-	V
Phototransistor Dark Current	$V_{CE}=5\text{V}, I_F=0\text{mA}$	I_{CEO}	-	50	500	A
Saturation Voltage	$I_C=2\text{mA}, I_F=16\text{mA}$	V_{SAT}	-	0.3	0.5	V
Current Transfer Ratio	$I_F=6\text{mA}, V_{CE}=0.5\text{V}$	CTR	33	400	-	%
Detector Portion (Pins 9,10)						
Input Characteristics @ 25°C						
Input Control Current	$I_C=2\text{mA}, V_{CE}=0.5\text{V}$	I_F	6	2	100	mA
Input Voltage Drop	$I_F=5\text{mA}$	V_F	0.9	1.2	1.4	V
Input Current (Detector must be off)	$I_C=1\mu\text{A}, V_{CE}=5\text{V}$	I_F	5	25	-	μA

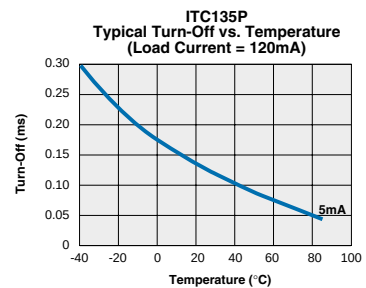
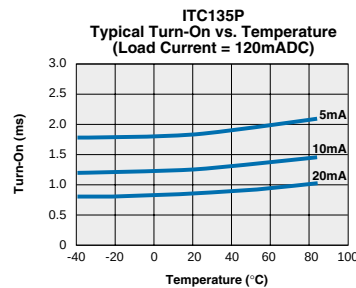
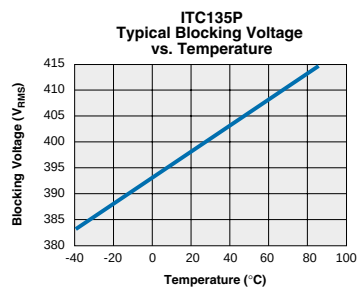
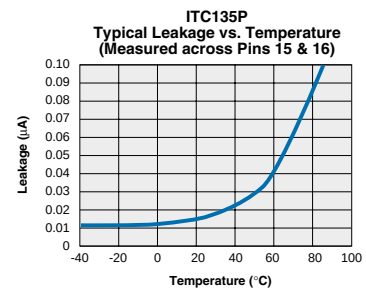
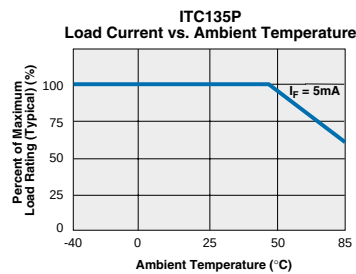
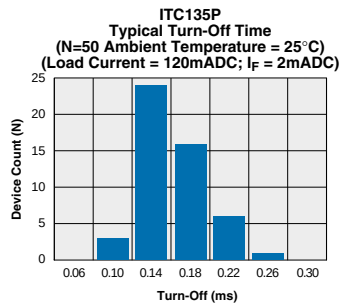
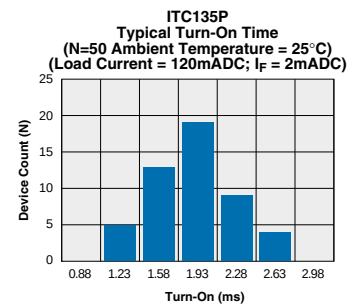
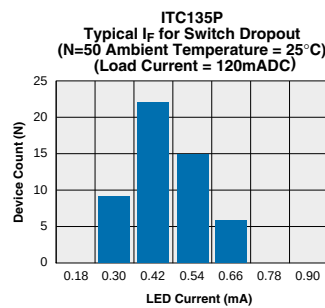
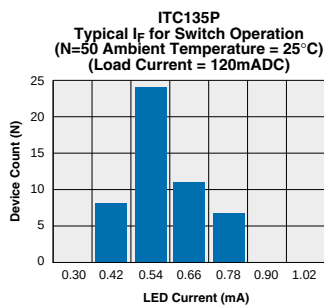
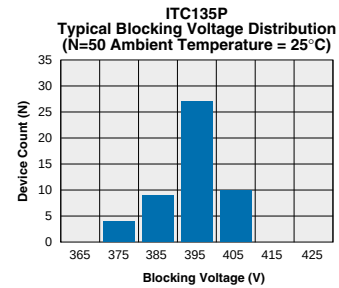
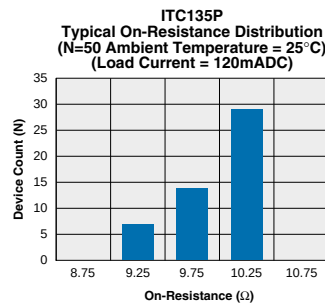
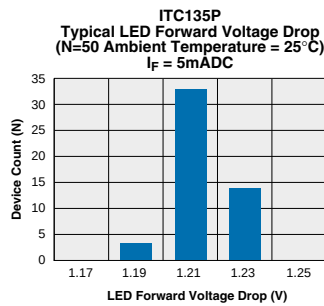
Electrical Characteristics

Parameter	Conditions	Symbol	Min	Typ	Max	Units
Bridge Rectifier Electrical Ratings @ 25°C						
Reverse Voltage	-	V_{RD}	-	-	100	V
Forward Drop Voltage	$I_{FD}=120\text{mA}$	V_{FD}	-	-	1.5	V
Reverse Leakage Current	$T_J=25^\circ\text{C}, V_R=100\text{V}$ $T_J=85^\circ\text{C}$	I_{RD}	-	-	10 50	μA μA
Forward Current (Continuous)	-	I_{FD}	-	-	140	mA
Forward Current (Peak)	$t=10\text{mS}$	I_{FD}	-	-	0.5	A
Darlington Electrical Ratings @ 25°C						
Collector-Emitter Voltage	$I_C=10\text{mA DC}, I_B=0$	V_{CE0}	40	-	-	V
Collector-Current Continuous	$V_C=3.5\text{V}$	I_C	-	-	120	mA
Power Dissipation @ 25°C	-	P_d	-	-	500	mW
Off-State Collector Emitter Leakage Current	$V_{CE}=10\text{V}; I_B=0\text{mA}$	I_{CEX}	-	-	1	μA
DC Current Gain	$I_C=120\text{mA}, V_{CE}=10\text{VDC}$	h_{FE}	10,000	-	-	
Saturation Voltage	$I_C=120\text{mA}$	$V_{CE(SAT)}$	-	-	1.5	V
Total Harmonic Distortion	$f_o=300\text{Hz @ -10dBm}$ $I_C=40\text{mA}$	-	-	-	-80	dB
Zener Characteristics @ 25°C						
Zener Voltage (Between pins 4+5 and 6+5)	$I_{ZT}=20\text{mA}$	V_Z	-	4.3	-	V
Zener Voltage (Between pins 12+11)	$I_{ZT}=20\text{mA}$	V_Z	-	15	-	V
Input to Output Capacitance	-	$C_{I/O}$	-	3	-	pF
Input to Output Isolation	-	$V_{I/O}$	3750	-	-	V_{RMS}

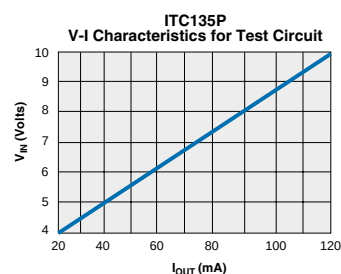
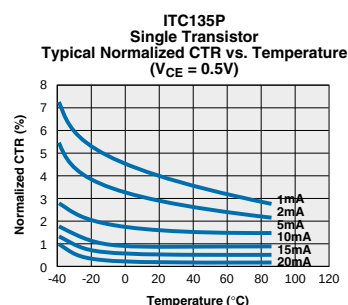
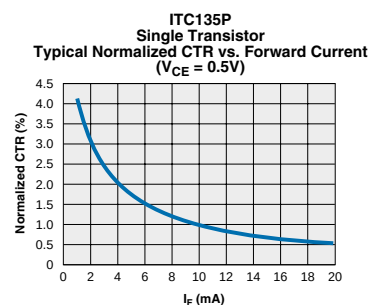
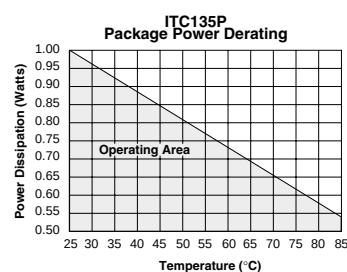
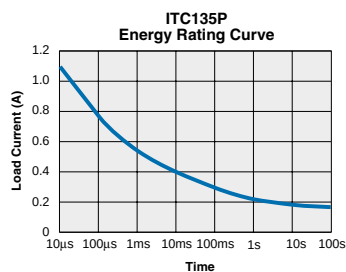
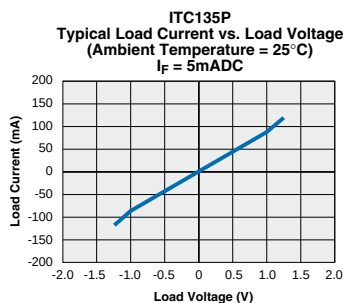
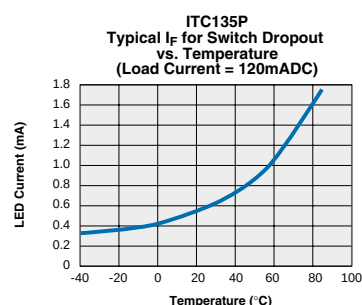
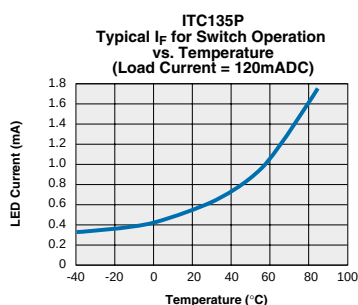
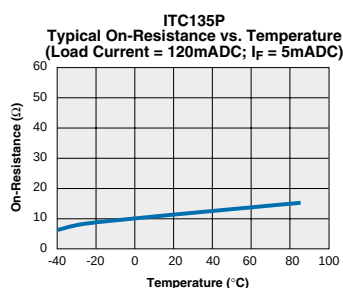
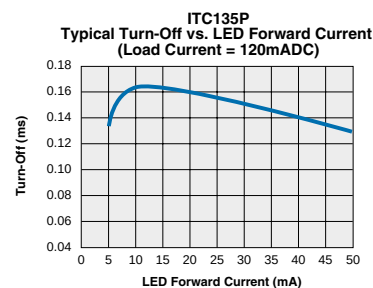
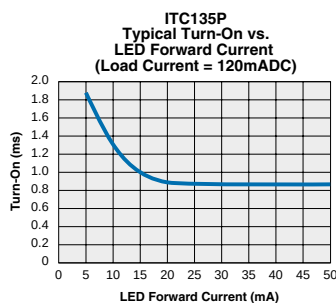
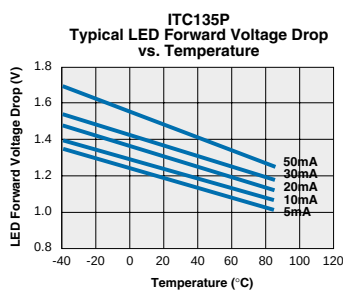
EXAMPLE CIRCUIT



PERFORMANCE DATA*

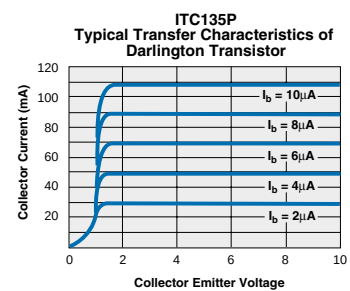
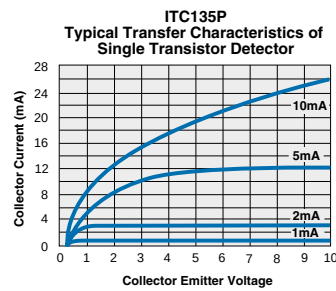
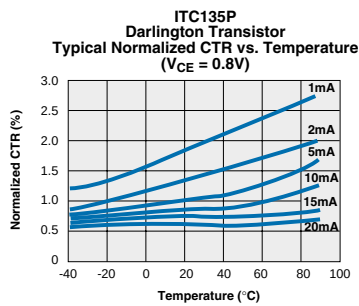
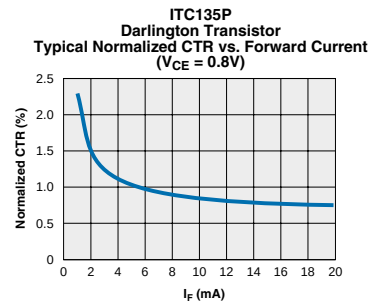
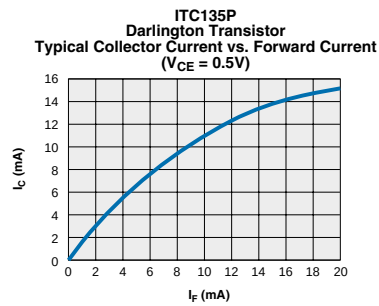
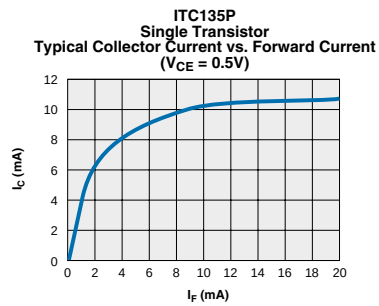


The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

PERFORMANCE DATA*


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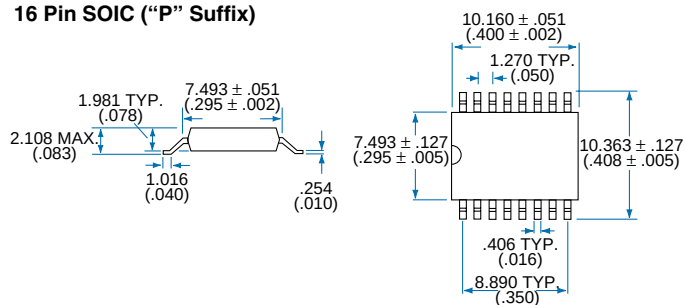
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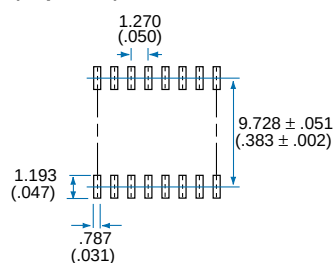
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Mechanical Dimensions

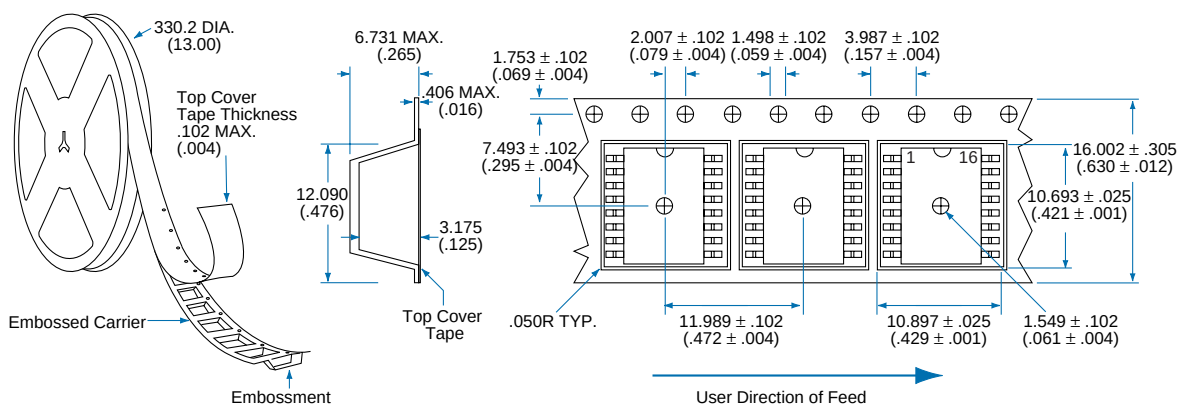
16 Pin SOIC ("P" Suffix)



PC Board Pattern (Top View)



Tape and Reel Packaging for 16 Pin SOIC Package



Dimensions
mm
(inches)



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